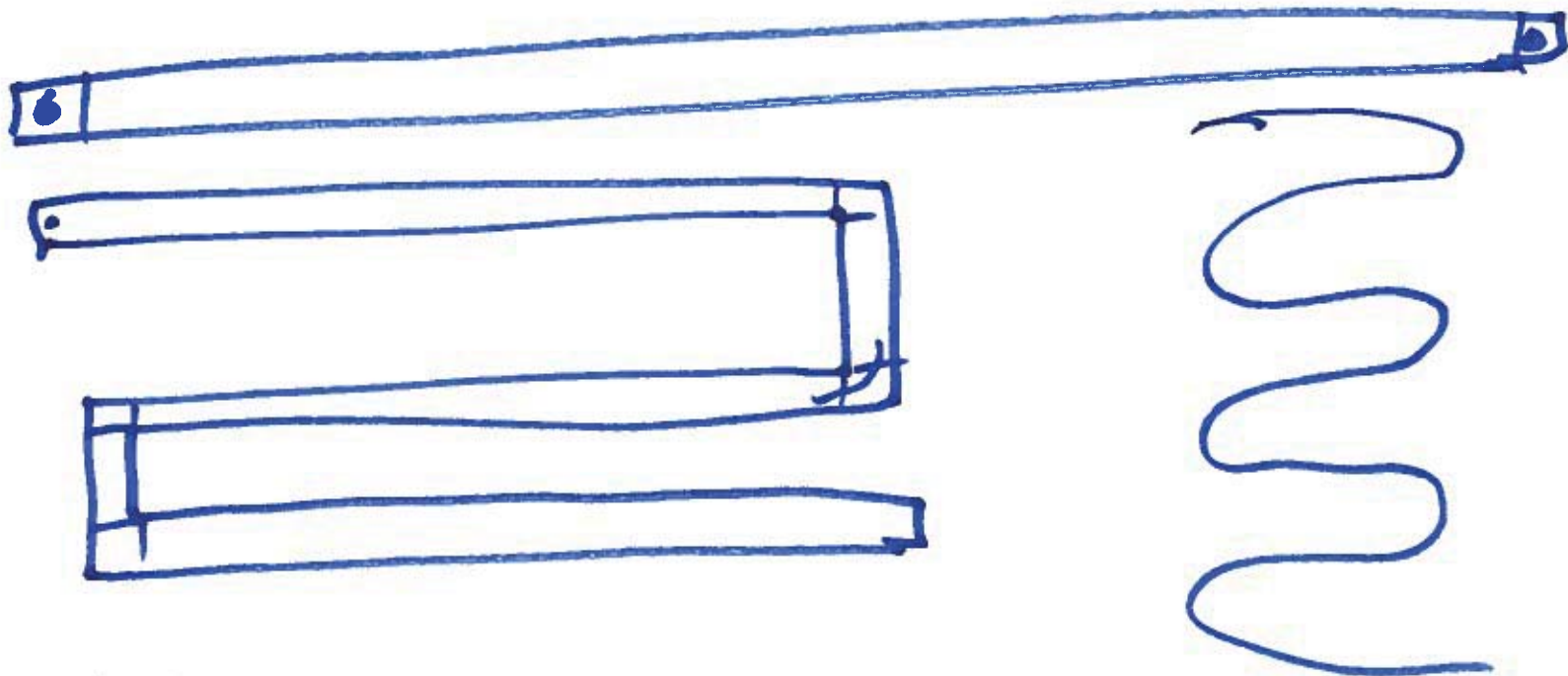
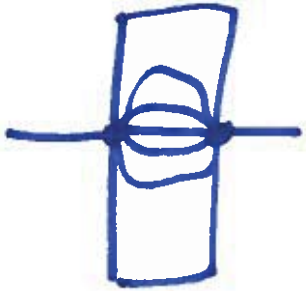


EE421 / ECE 621

Digital IC Design

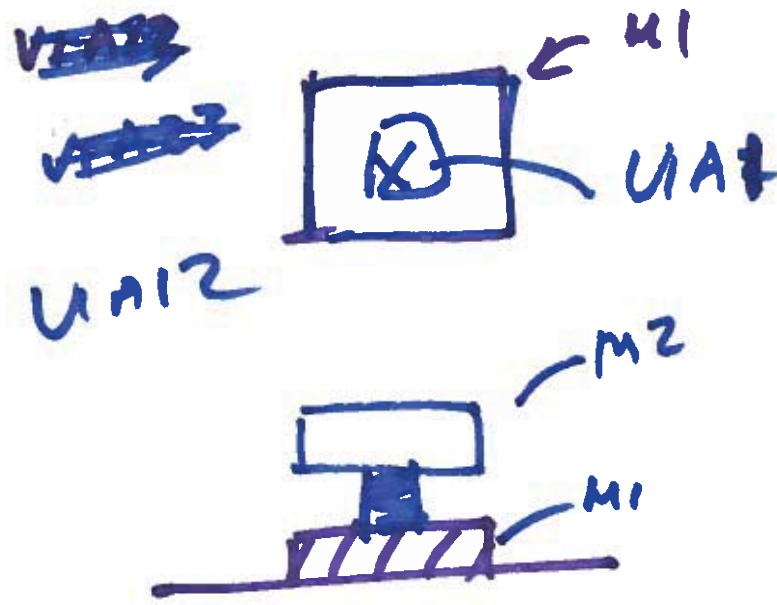
September 18, 2019

Lecture 7



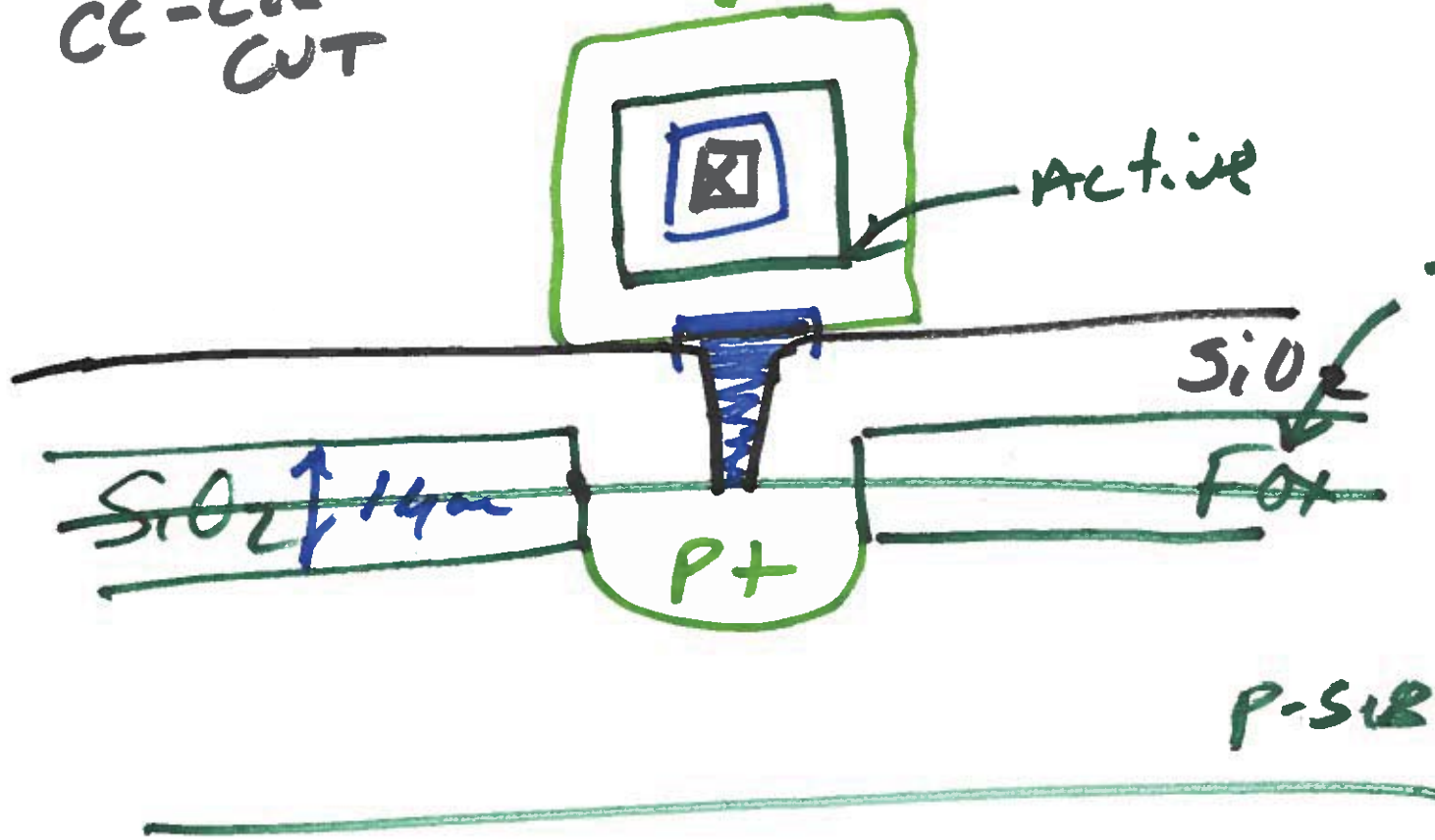
N-well
 Metal 3
 Glass
 Metal 2
 Metal 1
 VIA 2
 VIA 1

 CC



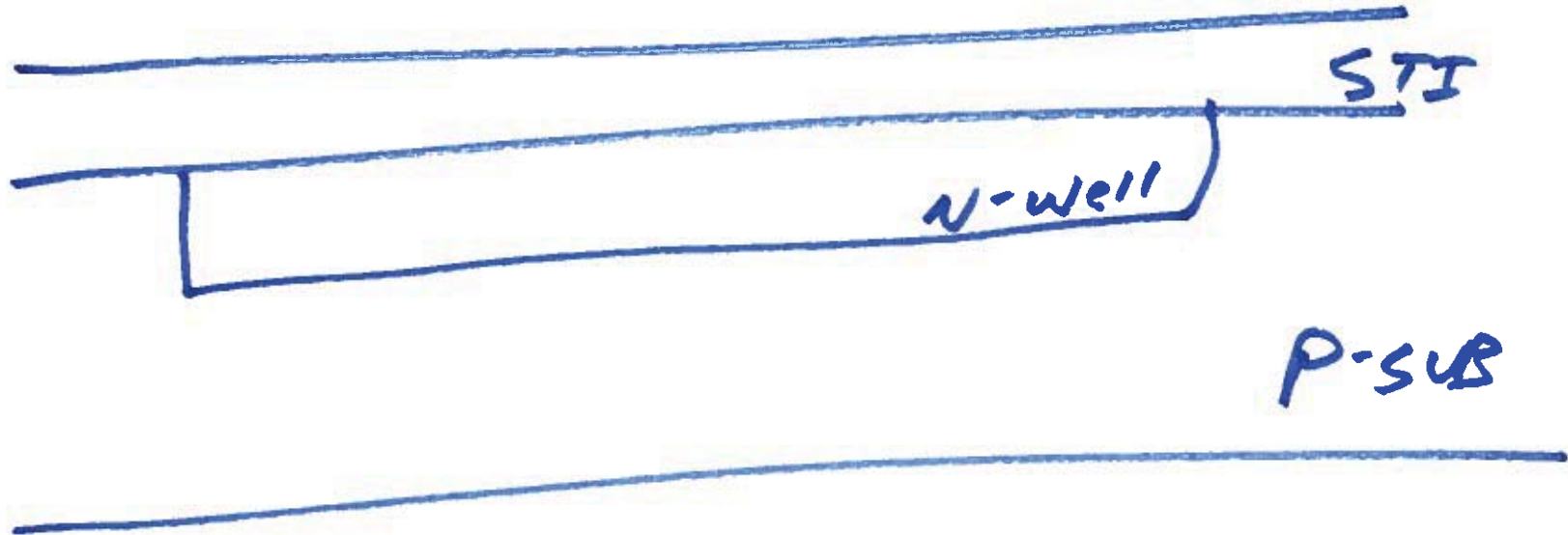
Active
p-select
CC-CONTACT
CUT

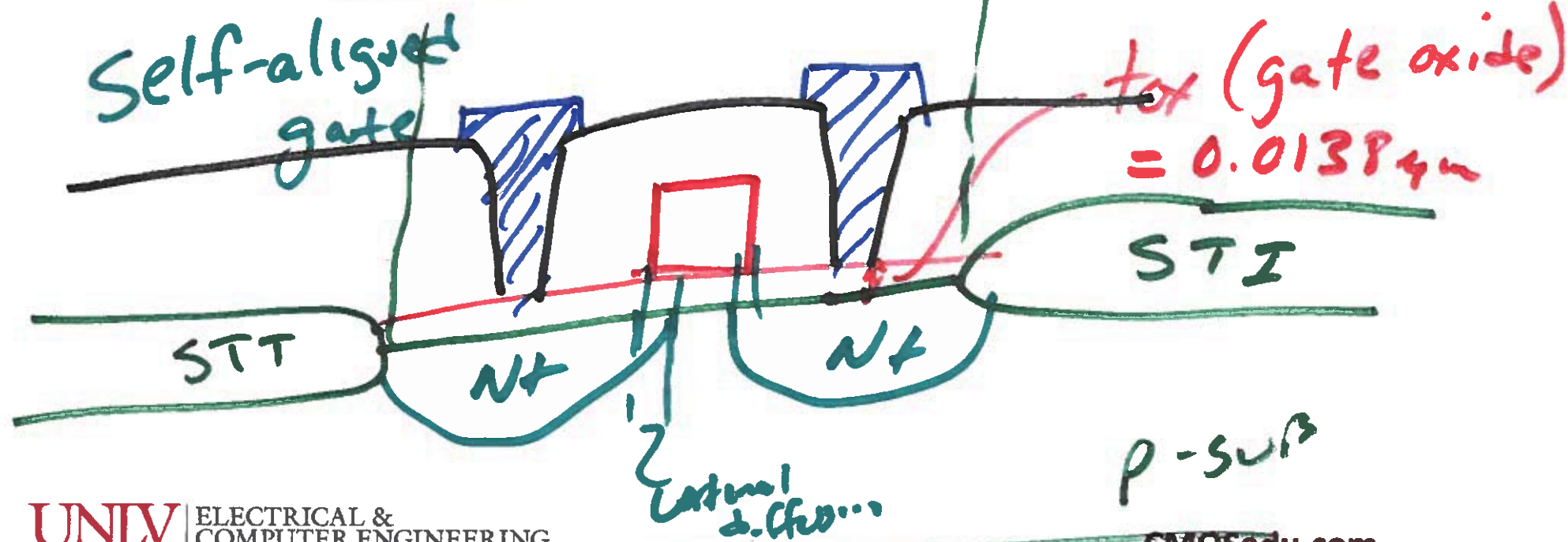
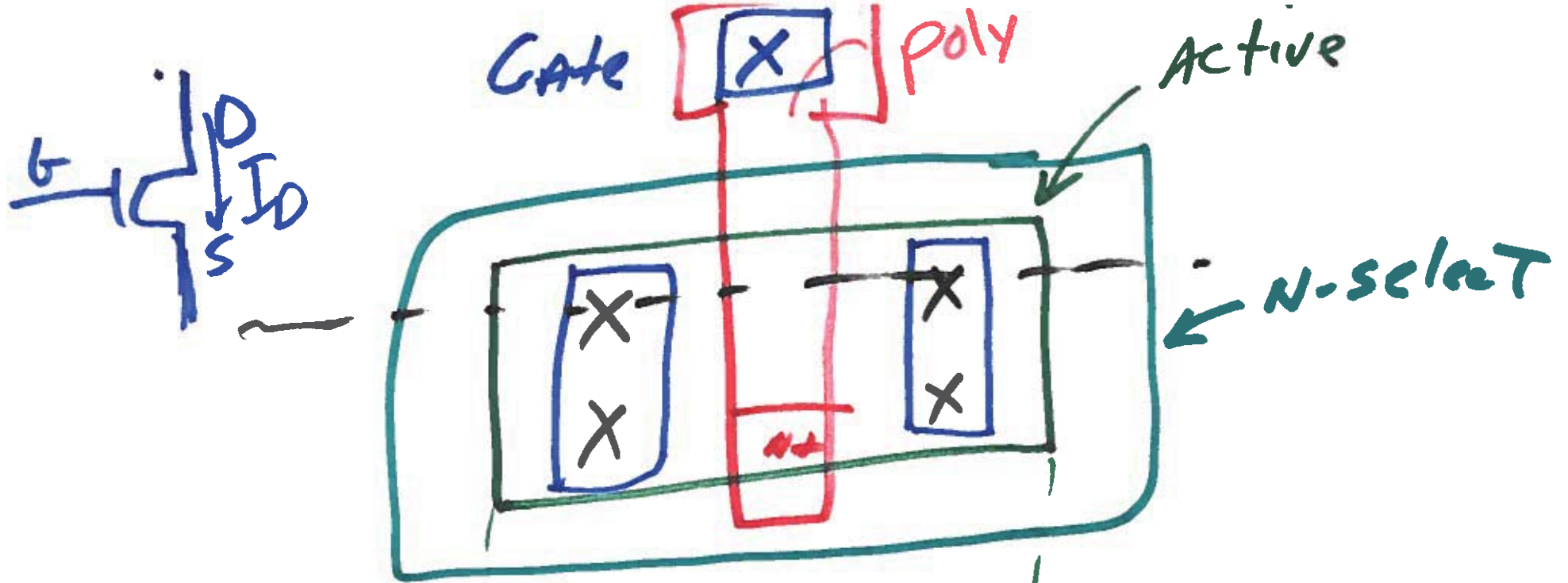
p-select



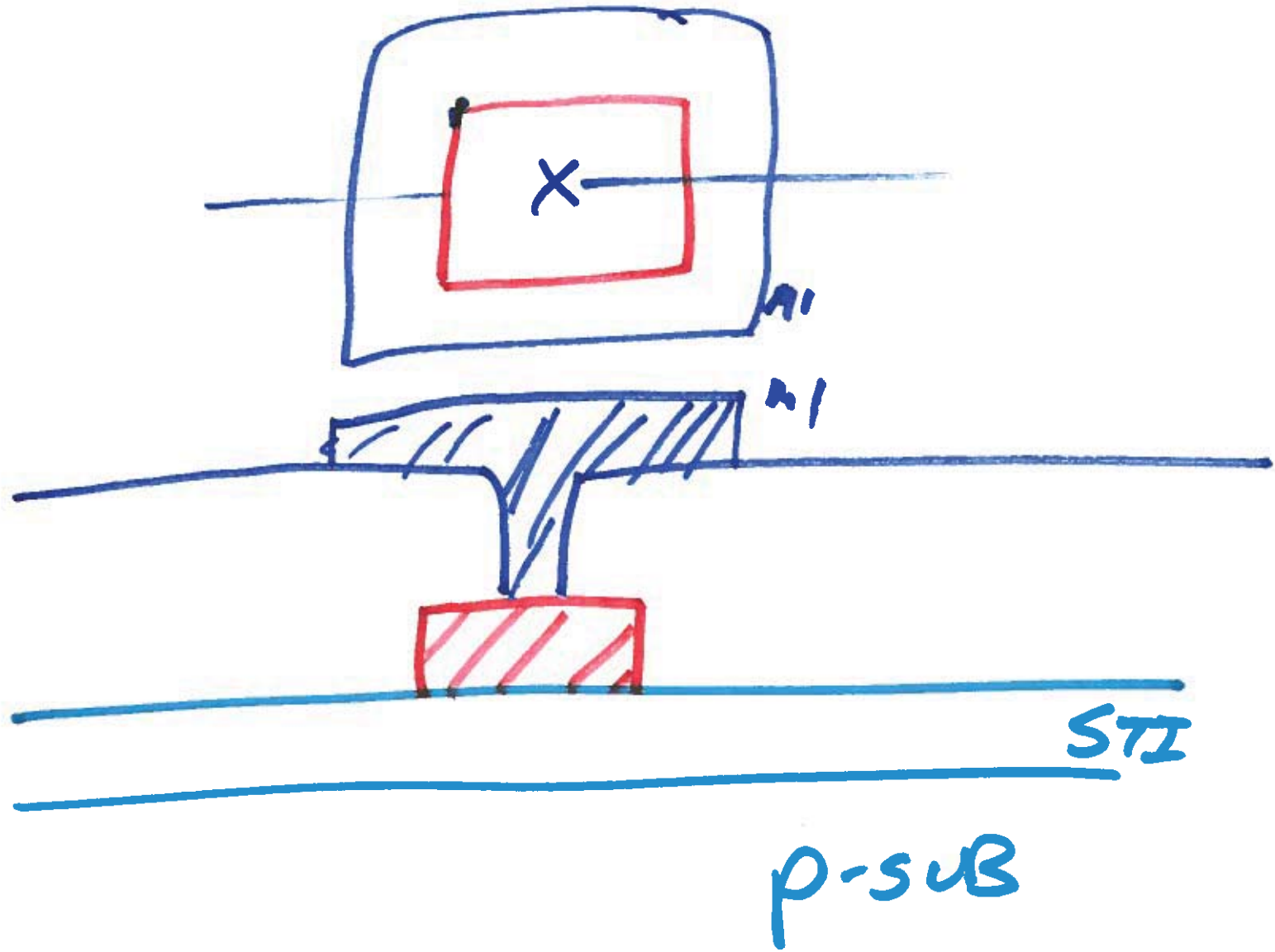
field.
oxide,
shallow
trench
isolation
(STI)

3)





5)



6)

